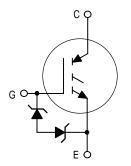
Designer's™ Data Sheet

Insulated Gate Bipolar Transistor

N-Channel Enhancement-Mode Silicon Gate

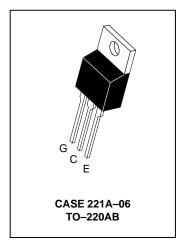
This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage–blocking capability. Its new 600 V IGBT technology is specifically suited for applications requiring both a high temperature short circuit capability and a low VCE(on). It also provides fast switching characteristics and results in efficient operation at high frequencies. This new E–series introduces an Energy–efficient, ESD protected, and short circuit rugged device.

- Industry Standard TO-220 Package
- High Speed: E_{off} = 65 μJ/A typical at 125°C
- High Voltage Short Circuit Capability 10 μs minimum at 125°C, 400 V
- Low On-Voltage 2.15 V typical at 20 A, 125°C
- · Robust High Voltage Termination
- ESD Protection Gate-Emitter Zener Diodes



MGP21N60E

IGBT IN TO-220
21 A @ 90°C
31 A @ 25°C
600 VOLTS
SHORT CIRCUIT RATED
LOW ON-VOLTAGE



MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCES	600	Vdc
Collector–Gate Voltage (R _{GE} = 1.0 MΩ)	VCGR	600	Vdc
Gate-Emitter Voltage — Continuous	VGE	±20	Vdc
Collector Current — Continuous @ T _C = 25°C — Continuous @ T _C = 90°C — Repetitive Pulsed Current (1)	I _{C25} I _{C90} I _{CM}	31 21 42	Adc Apk
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	140 1.12	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C
Short Circuit Withstand Time (V_{CC} = 400 Vdc, V_{GE} = 15 Vdc, T_J = 125°C, R_G = 20 Ω)	t _{sc}	10	μs
Thermal Resistance — Junction to Case – IGBT — Junction to Ambient	R _θ ЈС R _θ ЈА	0.9 65	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C
Mounting Torque, 6–32 or M3 screw	10 lbf•in (1.13 N•m)		

⁽¹⁾ Pulse width is limited by maximum junction temperature. Repetitive rating.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

Designer's is a trademark of Motorola, Inc.



MGP21N60E

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•			
Collector–to–Emitter Breakdown (V _{GE} = 0 Vdc, I _C = 25 μAdc) Temperature Coefficient (Positi	BVCES	600 —	 870	_	Vdc mV/°C	
Emitter-to-Collector Breakdown	B _{VECS}	15	_	_	Vdc	
Zero Gate Voltage Collector Curre (V _{CE} = 600 Vdc, V _{GE} = 0 Vdc) (V _{CE} = 600 Vdc, V _{GE} = 0 Vdc,			=	_	10 200	μAdc
Gate-Body Leakage Current (VG	IGES	_	_	50	μAdc	
ON CHARACTERISTICS (1)		•	•	•		
Collector-to-Emitter On-State Vo (V _{GE} = 15 Vdc, I _C = 10 Adc) (V _{GE} = 15 Vdc, I _C = 10 Adc, T _C (V _{GE} = 15 Vdc, I _C = 20 Adc)	VCE(on)	=	1.6 1.5 2.2	2.0 — 2.5	Vdc	
Gate Threshold Voltage (V _{CE} = V _{GE} , I _C = 1.0 mAdc) Threshold Temperature Coeffic	VGE(th)	4.0 —	6.0 10	8.0 —	Vdc mV/°C	
Forward Transconductance (VCE	9fe	_	8.6	_	Mhos	
DYNAMIC CHARACTERISTICS		•				
Input Capacitance		C _{ies}	_	1605	_	pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{oes}	_	146	_	
Transfer Capacitance] ,	C _{res}	_	23	_	
SWITCHING CHARACTERISTICS	(1)					
Turn-On Delay Time		^t d(on)	_	29	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 20 \text{ Adc},$	t _r	_	60	_	
Turn-Off Delay Time	V _{GE} = 15 Vdc, L = 300 μH, R _G = 20 Ω , T _J = 25°C)	td(off)	_	238	_	
Fall Time	Energy losses include "tail"	t _f	_	140	_	
Turn-Off Switching Loss		E _{off}	-	0.8	_	mJ
Turn-On Delay Time		^t d(on)	_	28	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 20 \text{ Adc},$	t _r	_	62	_	
Turn-Off Delay Time	V_{GE} = 15 Vdc, L = 300 μH, R _G = 20 Ω, T _J = 125°C)	td(off)	_	338	_	1
Fall Time	Energy losses include "tail"	t _f	-	220	_	1
Turn-Off Switching Loss	7	E _{off}	_	1.3	_	mJ
Gate Charge	(V _{CC} = 360 Vdc, I _C = 20 Adc, V _{GE} = 15 Vdc)	QT	_	86	_	nC
		Q ₁	_	18	_	1
	GE = 10 vao,	Q ₂	_	39	_	1
NTERNAL PACKAGE INDUCTAN	CE					
Internal Emitter Inductance (Measured from the emitter lead	LE	_	7.5	_	nH	

⁽¹⁾ Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

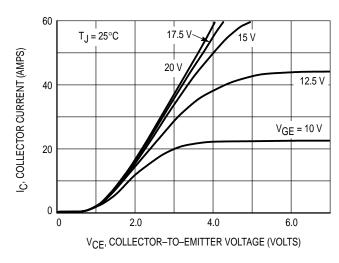


Figure 1. Output Characteristics, T_J = 25°C

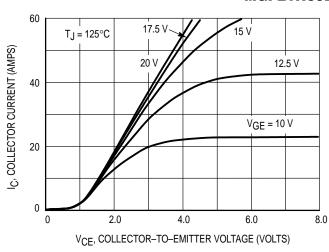


Figure 2. Output Characteristics, T_J = 125°C

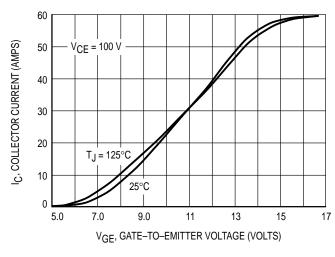


Figure 3. Transfer Characteristics

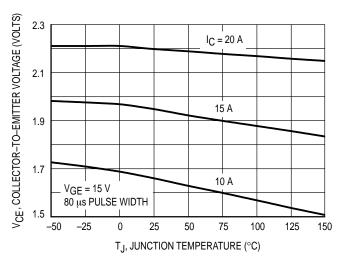


Figure 4. Collector–To–Emitter Saturation Voltage versus Junction Temperature

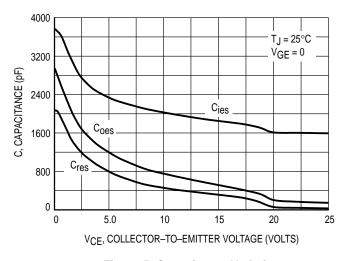


Figure 5. Capacitance Variation

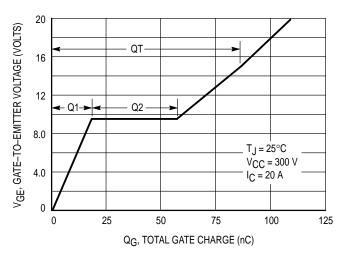


Figure 6. Gate-To-Emitter Voltage versus Total Charge

MGP21N60E

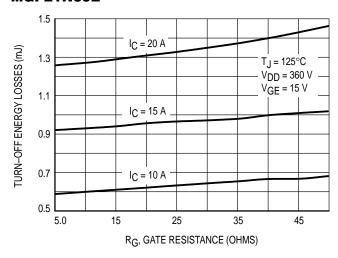


Figure 7. Turn–Off Losses versus
Gate Resistance

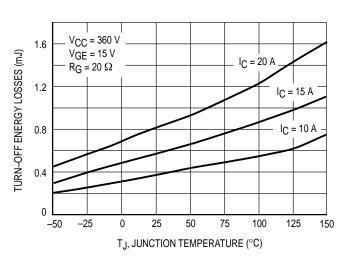


Figure 8. Turn-Off Losses versus Junction Temperature

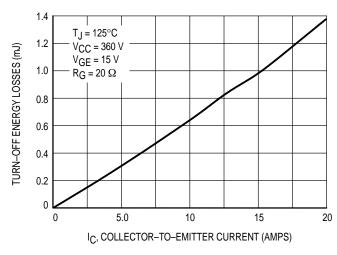


Figure 9. Turn-Off Losses versus Collector-To-Emitter Current

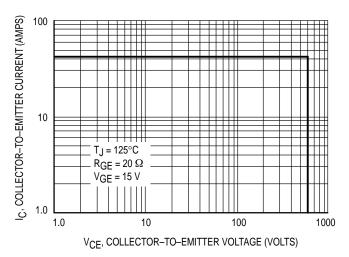
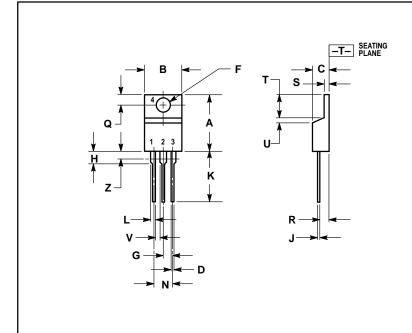


Figure 10. Reverse Biased Safe Operating Area

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IMETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15	_	
Z		0.080		2.04	

CASE 221A-06 TO-220AB **ISSUE Y**

MGP21N60E

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447

Mfax™: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 **AS**– US & Canada ONLY 1–800–774–1848 51

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4–32–1, Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81–3–5487–8488

TOUCHTONE 602–244–6609
 ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,
 US & Canada ONLY 1–800–774–1848
 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

Mfax is a trademark of Motorola. Inc.

INTERNET: http://motorola.com/sps



MGP21N60E/D